## IN THE CLAIMS:

Claims 1, 4, 6, 8, and 9 have been amended herein. All of the pending claims 1 through 10 are presented below. This listing of claims will replace all prior versions and listings in the application. Please enter these claims as amended.

1. (Currently Amended) A semiconductor assembly comprising:
a substrate having a plurality of circuits on a portion of a surface thereof;
a semiconductor die having a plurality of bond pads located on an active surface thereof and having a back side surface;

a plurality of solder balls connecting at least a portion of the plurality of bond pads of the semiconductor die to at least a portion of the plurality of circuits of the substrate; one of a glob top material and and a low viscosity polymeric material filing filling any space between the substrate and the semiconductor die;

a gel-elastomer contacting at-least-a portion of the back-side surface to father semiconductor, die, wherein the gel elastomer is compliant, adhesive, and filled with a thermally conductive material; and

a heat sink cap covering the gel elastomer, the semiconductor die, the plurality of solder balls, and a portion of the substrate, the heat sink cap contacting at least a portion of the gel elastomer.

2. (Original) The semiconductor assembly of claim 1, wherein the heat sink cap includes a plurality of fins thereon.

3. (Original) The semiconductor assembly of claim 1, wherein the gel elastomer includes a cross-linked silicone.

4. (Currently Amended) A semiconductor assembly comprising: a substrate having a surface having a plurality of circuits on a portion thereof;

- a semiconductor die having a plurality of bond pads located on a first portion of an active surface thereof and having a back side surface;
- a plurality of solder balls connecting at least a portion of the plurality of bond pads of the semiconductor die to at least a portion of the plurality of circuits of the substrate;
- one of a glob top material and a low viscosity polymeric material filling filling any space between the substrate and the semiconductor die;
- a gel elastomer contacting a portion of the back side surface of the semiconductor die, wherein the gel elastomer is a cross-linked-silicon silicone gel, compliant, adhesive, and filled with a thermally conductive material; and
- a heat sink cap having a portion thereof in contact with a portion of the gel elastomer, the heat sink cap covering the gel elastomer, the semiconductor die, the plurality of solder balls, and at least a portion of the substrate.
- 5 (Original) The semiconductor assembly of claim 4, wherein the heat sink cap includes a plurality of fins thereon.
  - 6. (Currently Amended) An assembly comprising:
- a substrate having a plurality of circuits on a portion thereof;
- a semiconductor die having a plurality of bond pads located thereon and having a back side surface;
- a plurality of solder balls connecting at least a portion of the plurality of bond pads of the semiconductor die to at least a portion of the plurality of circuits of the substrate;
- one of a glob top material-and and a low viscosity polymeric material-filing filling any space between the substrate and the semiconductor die;
- a compliant, adhesive, and filled with a thermally conductive material material, gel elastomer contacting at least a portion of the back side surface of the semiconductor die; and
- a heat sink cap covering the compliant, adhesive, and filled with a thermally conductive material material, gel elastomer, the semiconductor die, the plurality of solder balls, and a portion of the substrate, the heat sink cap contacting at least a portion of the gel elastomer.

- 7. (Original) The semiconductor assembly of claim 6, wherein the heat sink cap includes a plurality of fins thereon.
- 8. (Currently Amended) The semiconductor assembly of claim 6, wherein the compliant, adhesive, and filled with a thermally conductive material material, gel elastomer includes a cross-linked silicone.
- 9. (Currently Amended) An assembly comprising: a substrate having a plurality of circuits on a portion thereof;
- a semiconductor die having a plurality of bond pads and having a back side surface;
- a plurality of solder balls connecting at least a portion of the plurality of bond pads of the semiconductor die to at least a portion of the plurality of circuits of the substrate; one of a glob top material and a low viscosity polymeric material filling filling any space

between the substrate and the semiconductor die:

- a compliant, adhesive, and filled with a thermally conductive material material, gel elastomer contacting a portion of the back side surface of the semiconductor die; die, and a heat sink cap having a portion thereof in contact with a portion of the compliant, adhesive, and filled with a thermally conductive material material, gel elastomer, the heat sink cap covering the compliant, adhesive, and filled with a thermally conductive material material, gel elastomer, the semiconductor die, the plurality of solder balls, and at least a portion of the substrate.
- 10. (Original) The semiconductor assembly of claim 9, wherein the heat sink cap includes a plurality of fins thereon.